

# iscN-Channel MOSFET Transistor

**TK13P25D** 

#### • FEATURES

• Low drain-source on-resistance:  $R_{DS}(ON) = 0.19\Omega$  (typ.) (Vgs = 10 V)

Enhancement mode:
Vth = 1.5 to 3.5V (VDS = 10 V, ID=1.0mA)

- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



Switching Voltage Regulators

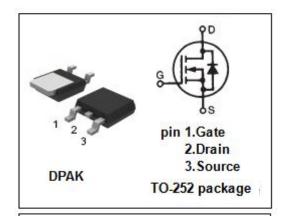


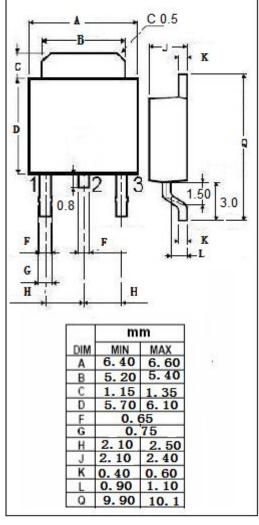
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	250	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	13	А
І <sub>ОМ</sub>	Drain Current-Single Pulsed	52	А
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	96	W
Тј	Max. Operating Junction Temperature 150		°C
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.3	°C/W







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### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	250			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	1.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =6.5A			250	mΩ
Igss	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 250V; V <sub>GS</sub> = 0V			10	μА
$V_{SDF}$	Diode forward voltage	I <sub>DR</sub> =13A, V <sub>GS</sub> = 0 V			1.7	V



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